

# VFSA010R110NA

Datasheet

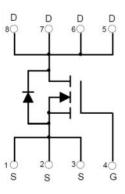
# VMDSEMI



### VFSA010R110NA

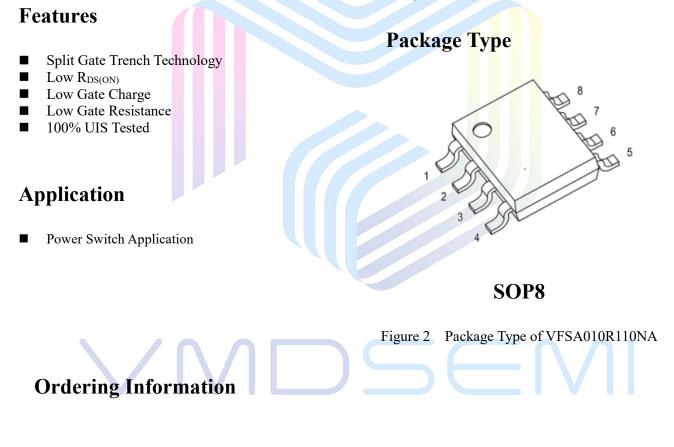
### **General Description**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)_max</sub>	I <sub>D</sub>
100V	11mΩ@10V	14A



Symbol

#### Figure 1 Symbol of VFSA010R110NA



Product Name	Package		
VFSA010R110NA	SOP8		



### VFSA010R110NA

# Absolute Maximum Ratings (T<sub>A</sub>= 25 °C, unless otherwise specified)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DSS</sub>	100	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current <sup>Note1</sup> $T_A = 25 \text{ °C}$	ID	14	
Pulsed Drain Current Note2	I <sub>DM</sub>	56	A
Avalanche Current <sup>Note3</sup>	I <sub>AS</sub>	11	
Single Pulsed Avalanche Energy <sup>Note3</sup>	E <sub>AS</sub>	30	mJ
Total Power Dissipation <sup>Note5</sup> $T_A = 25 \text{ °C}$	PD	3.1	W
Junction Temperature	TJ	150	°C
Storage Temperature	Tstg	-55 to 150	°C

# Thermal Resistance

Parameter		Symbol	Min	Т <mark>у</mark> р	Max	Unit
Thermal Resistance, Junction-to-Ambient Note6		R <sub>0JA</sub>		40		°C/W

# VMDSEMI



### VFSA010R110NA

Symbol	Test Conditions	Min	Тур	Max	Unit		
Statistic Characteristics							
BV <sub>DSS</sub>	$V_{GS}=0V, I_D=250uA$ 100				V		
I <sub>DSS</sub>	$V_{DS}=100V, V_{GS}=0V$			1	uA		
I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100	nA		
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 uA$ 1.0		2.5	3.0	V		
R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> = 10A		8	11	mΩ		
Dynamic Characteristics							
CISS	V <sub>DS</sub> =50V		1929		pF		
Coss	V <sub>GS</sub> =0V		617		pF		
C <sub>RSS</sub>	f=1MHz		18		pF		
Qg	V <sub>DS</sub> =50V		39.8				
Qgs	V <sub>GS</sub> =10V		7.1		nC		
Qgd	$I_D = 10A$		11.9				
Rg	f = 1MHz, Open drain		1.7		Ω		
t <sub>d(on)</sub>	$V_{DD}=50V$		9				
tr	$V_{GS}=10V$		4				
t <sub>d(off)</sub>	$R_L=4.15\Omega$		25		ns		
tf	$R_{G}=2.7\Omega$ 4						
V <sub>SD</sub>	$V_{GS}=0V, I_{S}=10A$			1.2	V		
	BV <sub>DSS</sub> I <sub>DSS</sub> I <sub>GSS</sub> V <sub>GS(th)</sub> R <sub>DS(ON)</sub> C <sub>ISS</sub> C <sub>RSS</sub> C <sub>RSS</sub> Q <sub>g</sub> Q <sub>g</sub> Q <sub>g</sub> Q <sub>g</sub> Q <sub>g</sub> Rg t <sub>d(on)</sub> t <sub>r</sub> t <sub>d(off)</sub>	$\begin{array}{ c c c c c } BV_{DSS} & V_{GS}=0V, I_{D}=250uA \\ \hline I_{DSS} & V_{DS}=100V, V_{GS}=0V \\ \hline I_{GSS} & V_{GS}=\pm 20V, V_{DS}=0V \\ \hline V_{GS(th)} & V_{DS}=V_{GS}, I_{D}=250uA \\ \hline R_{DS(ON)} & V_{GS}=10V, I_{D}=10A \\ \hline \\ $	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$		

### Electrical Characteristics (T<sub>J</sub>= 25 °C, unless otherwise specified)

Notes :

1. The maximum current rating is limited by package. And device mounted on a large heatsink.

2.Pulse Test : Pulse Width  $\leq 10\mu s$ , duty cycle  $\leq 1\%$ .

 $3.E_{AS}$  condition:  $V_{DD} = 50V$ ,  $V_{GS} = 10V$ , L = 0.5mH,  $R_G = 25\Omega$  Starting  $T_J = 25^{\circ}C$ .

4. Pulse Test : Pulse Width  $\leq$  300µs, duty cycle  $\leq$  2%.

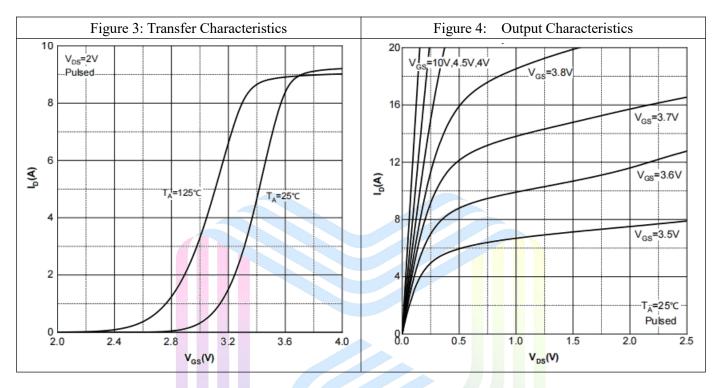
5. The power dissipation  $P_D$  is limited by  $T_{J(MAX)} = 150^{\circ}$ C. And device mounted on a large heatsink

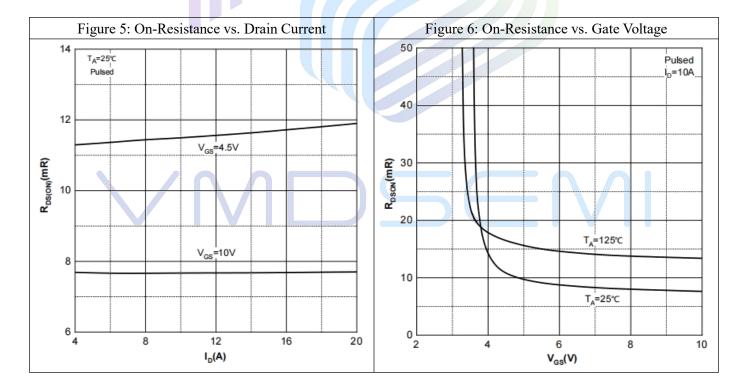
6.Device mounted on  $1in^2$  FR-4 board with 2oz. Copper, in a still air environment with  $T_A = 25^{\circ}C$ .



### VFSA010R110NA

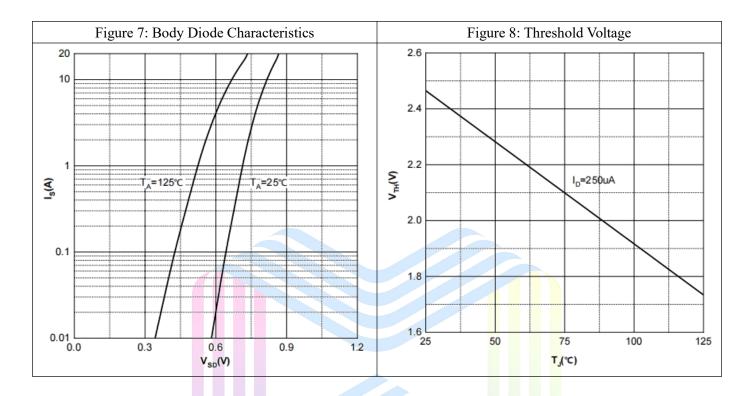
# **Typical Performance Characteristics**







### VFSA010R110NA



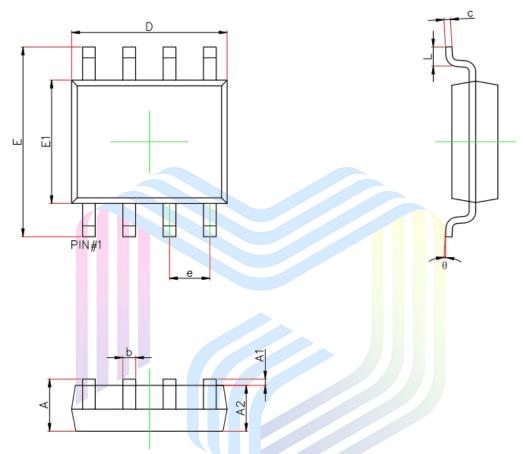
# VMD5EMI



### VFSA010R110NA

# **Mechanical Dimensions:**

### **SOP8** Package Information



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.156	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.201	
е	1.270(BSC)		0.050	(BSC)	
E	5.800	6.200	0.228	0.244	
E1	3.700	4.100	0.146	0.161	
L	0.400	1.270	0.016	0.05	
θ	0°	8°	0°	8°	



### VFSA010R110NA

### NOTICE

Hangzhou VMD Semiconductor Co., Ltd (VMD) reserves the right to make changes without notice in order to improve reliability, function or design and to discontinue any product or service without notice. Customers should obtain the latest relevant information before orders and should verify that such information is current and complete. All products are sold subject to VMD's terms and conditions supplied at the time of order acknowledgement.

VMD, its affiliates, agents, and employees, and all persons acting on its or their behalf, disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

VMD disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify VMD's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

VMD warrants performance of its hardware products to the specifications at the time of sale, testing, reliability and quality control are used to the extent VMD deems necessary to support this warrantee. Except where agreed upon by contractual agreement, testing of all parameters of each product is not necessarily performed.

VMD does not assume any liability arising from the use of any product or circuit designs described herein. Customers are responsible for their products and applications using VMD's components. To minimize risk, customers must provide adequate design and operating safeguards.

VMD does not warrant or convey any license to any intellectual property rights either expressed or implied under its patent rights, nor the rights of others. Reproduction of information in VMD's data sheets or data books is permissible only if reproduction is without modification or alteration. Reproduction of this information with any alteration is an unfair and deceptive business practice.

VMD is not responsible or liable for such altered documentation. Resale of VMD's products with statements different from or beyond the parameters stated by VMD for that product or service voids all express or implied warrantees for the associated VMD product or service and is an unfair and deceptive business practice.

All Rights Reserved.

# VMD5EMI



# Via-Media Semiconductor Limited Company

## http://www.vmdsemi.com

#### Main Sites:

#### - Headquarters

Hangzhou Via-Media Semiconductor Co., LTD. 1305-1306, Building 71, No. 90, Wensan Road, Xihu District, Hangzhou, Zhejiang Province, P.R. China Tel: +86-0571-8515 0563

#### - Shanghai

Shanghai R&D Center. 1506~1508, Xinyin Building, 888 Yishan Road, Shanghai, P.R of China Tel: +86- 021-54201999

### - Xi'an

Xi'an R&D Center 1703B, Building A, Greenland Center, Jinye Road, High-Tech Zone, Xi'an, Shaanxi, P.R of China

### Chengdu Office

Chengdu Winhi Semiconductor Co., LTD. Floor 15, Building 5, No. 171, Hele 2<sup>nd</sup> Street, Chengdu, Sichuan Province, P.R. China Tel: +86-028-8505 0771

### - Shenzhen

Shenzhen Sales Center. 17B, No.1 Phoenix Building, 2008 Shennan Road, Shenzhen, P.R of China Tel: +86-0755- 82570682